# PHYS 215C In-Class Notes

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## 1 Scattering

#### 1.1 Suggested References

- Sakurai Ch. 6
- Shankar Ch. 19
- Merzbacher Ch. 11

#### 1.2 Basic Setup

The basic idea in scattering theory is a particle being scattered into a target (particle into target). Other models model two particles moving towards each other and scattering off each other (particle into particle).

#### 1.2.1 Applications

Particle into particle scattering is very prevalent in high energy physics studies (particle accelerators), with traditional subatomic particles like electrons, neutrons, and protons.

Target scattering is used to model particle-particle interactions (particle physics), atoms and ions (atomic/nuclear physics), and interactions within a solid or liquid (condensed matter physics).

## 1.3 Scattering Approach to $e^-$ Transport in solids

#### 1.3.1 Setup

In this theory we talk about the conduction of electrons in a metal or doped semiconductor. The canonical experiment is a battery providing a potential difference across the material of interest. The conductance, G = I/V = 1/R, is what is of interest. There are impurities in the metal or semiconductor that cause scattering of the electrons that are moving under the influence of the potential difference.

#### 1.3.2 Rolf Landauer's Theory (Landauer Transport Theory)

**Toy Model** Consider a one-dimensional scattering potential that is a finite potential barrier between x = a and x = -a with incident electrons coming from the left with average energy E. (This is actually very relevant in a gated two-dimensional electron gas, where the low energies only allow one mode on the surface dimension.) The theory of this problem is well understood in terms of transmission and reflection coefficients (see the appendix in Sakurai). We will look at the *steady state* system.

First divide the region up into three regions. Region I is  $-\infty < x < -1$ , region II is -a < x < a, and region III is  $a < x < \infty$ . This gives rise to three wave functions of interest.

$$\psi_{\rm I} = A_{\rm in}e^{ikx} + A_{\rm out}e^{-ikx}$$
  
$$\psi_{\rm II} = C_1e^{ik'x} + C_2e^{-ik'x}$$
  
$$\psi_{\rm III} = B_{\rm out}e^{9kx} + B_{\rm in}e^{-ikx}$$

where

$$k = \frac{1}{\hbar}\sqrt{2mE}$$
  $k' = \frac{1}{\hbar}\sqrt{2m(E-V)}$ 

Normally we would solve for these wave functions by matching  $\psi$  and  $\psi'$  at the boundaries to relate A, B, and C. We can represent the solution via a transfer matrix:

$$\left(\begin{array}{c} B_{\rm out} \\ B_{\rm in} \end{array}\right) = \left(\begin{array}{cc} M_{11} & M_{12} \\ M_{21} & M_{22} \end{array}\right) \left(\begin{array}{c} A_{\rm in} \\ A_{\rm out} \end{array}\right)$$

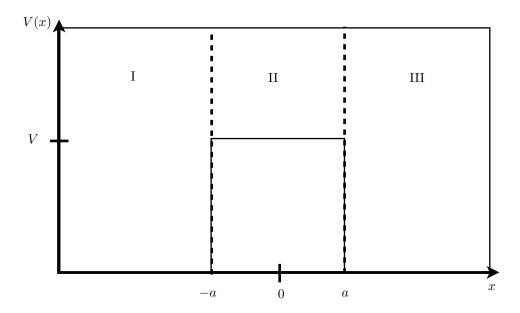


Figure 1: 1-D Scattering Potential

Alternatively, we may use the less clear S-matrix:

$$\begin{pmatrix} A_{\text{out}} \\ B_{\text{out}} \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \begin{pmatrix} A_{\text{in}} \\ B_{\text{in}} \end{pmatrix}$$

The system obeys an equation of continuity (probability conservation):

$$\partial_t \left| \psi \right|^2 + \partial_x J = 0$$

where

$$J = \frac{\hbar}{m} \operatorname{Im} \left( \psi^* \partial_x \psi \right)$$

The currents in regions I and III gives

$$J_{\rm I} = \frac{\hbar k}{m} \left[ \left| A_{\rm in} \right|^2 - \left| A_{\rm out} \right|^2 \right]$$
$$J_{\rm III} = \frac{\hbar k}{m} \left[ \left| B_{\rm out} \right|^2 - \left| B_{\rm in} \right|^2 \right]$$

The equation of continuity then tells us that

$$\begin{aligned} \left|A_{\rm out}\right|^2 + \left|B_{\rm out}\right|^2 &= \left|A_{\rm in}\right|^2 + \left|B_{\rm in}\right|^2 \\ \left(\begin{array}{cc} A_{\rm out}^* & B_{\rm out}^* \end{array}\right) \left(\begin{array}{cc} A_{\rm out} \\ A_{\rm out} \end{array}\right) &= \left(\begin{array}{cc} A_{\rm in}^* & B_{\rm in}^* \end{array}\right) S^{\dagger} S \left(\begin{array}{cc} A_{\rm in} \\ B_{\rm in} \end{array}\right) \end{aligned}$$

For scattering states, we let  $B_{\rm in}=0$ , that is, particles are *only* incident from the left. Then we have

$$\psi_k(x) = \begin{cases} A_{\text{in}} e^{ikx} + A_{\text{out}} e^{-ikx} & x < -a \\ B_{\text{out}} e^{ikx} & x > a \end{cases}$$

and we have

$$B_{\text{out}} = S_{21}A_{\text{in}}$$
$$A_{\text{out}} = S_{11}A_{\text{in}}$$

We define transmission and reflection coefficients

$$T \equiv \frac{|B_{\text{out}}|^2}{|A_{\text{in}}|^2} = |S_{21}|^2$$

$$R \equiv \frac{|A_{\text{out}}|^2}{|A_{\text{in}}|^2} = |S_{11}|^2$$

#### Landauer Formula

$$G = \frac{I}{V} \Rightarrow G = \frac{e^2}{h}T$$

where  $e^2/h$  is the quantum of conductance.

March 30, 2011

#### Derivation of the Landauer Formula

Suppose we send in a wave with wave number k and energy  $E = \hbar^2 k^2 / 2m$  from the left. As expected, we would get a portion of the wave to be reflected (proportional to  $S_{11}$ ) the remainder to to be transmitted (proportional to  $S_{21}$ ).

The Scattering State is then given by

$$\psi_1^k(x) = \begin{cases} \frac{e^{i\phi_1 k}}{\sqrt{2\pi}} \left( e^{ikx} + S_{11}e^{-ikx} \right) & x < -a \\ \frac{e^{\phi_1 k}}{\sqrt{2\pi}} S_{21}e^{ikx} & x > a \end{cases}$$

$$\psi_2^k(x) = \begin{cases} \frac{e^{i\phi_2 k}}{\sqrt{2\pi}} \left( e^{ikx} + S_{22}e^{ikx} \right) & x > a\\ \frac{e^{\phi_2 k}}{\sqrt{2\pi}} S_{12}e^{-ikx} & x < -a \end{cases}$$

With this, we are ready to...

For T=0, we have incident electrons up to chemical potential  $\mu$ . On different leads on a quantum wire, we generally have two different chemical potentials, which causes a net transport of electrons. Suppose on the left we have  $\mu_1$  and on the right we have  $\mu_2$  with  $\mu_1 < \mu_2$ , which causes an electrical net current from left to right. Our goal is to study this current in terms of the S-matrix.

Fermi Wave Number We define the Fermi Wave Number by

$$k_F = \frac{1}{\hbar} \sqrt{2m\mu}$$

The probability current for  $e^{-1}$  at k is given by

$$J_j^k = \frac{\hbar}{m} \operatorname{Im} \left[ \psi_j^{k^*}(x) \partial_x \psi_j^k(x) \right]$$

The electrical current is then

$$I|_{x>a} = eJ_j^k = e\frac{\hbar}{m} \left[ \int_0^{k_{F_1}} dk \, \frac{k}{2\pi} \, |S_{21}|^2 + \int_0^{k_{F_2}} dk \frac{k}{2\pi} \left( -1 + |S_{22}|^2 \right) \right]$$

Then the transmission probability if  $T_k \equiv |S_{21}|^2$ , which gives the current to be

$$I = \frac{e}{2\pi} \int_{k_{F_2}}^{k_{F_1}} dk \left(\frac{\hbar k}{m}\right) T_k = \frac{3}{2\pi\hbar} \int_{\mu_2}^{\mu_1} dE \, T(E)$$

Where we have used  $E = \hbar 2k^2/2m$  and  $dE = (\hbar^2 k/m) dk$ . We may relate the two chemical potentials to the electric voltage via

$$\mu_1 = \mu_2 + eV$$

**Linear Response** The conductance is given by

$$G = \lim_{V \to 0} \frac{I}{V}$$

Then the electric current can be rewritten as

$$I = \frac{e}{2\pi\hbar} \int_{\mu_2}^{\mu_2 + eV} dE \, T(e) = \frac{e^2}{h} T(\mu) V \label{eq:I}$$

and then the conductance in this linear response limit is

$$G = \frac{I}{V} = \frac{e^2}{h}T(\mu) = \frac{e^2}{h}T(E_F)$$

#### 1.3.3 Some Comments

- 1. Suppose we have a perfect wire with no backscattering. That is, T=1. Then we have  $R=\frac{1}{G}=0$ . This would of course be superconductivity.
- 2. This theory can be generalized to multichannel wires with many leads. The resulting conductance for N leads is then

$$G = \frac{e^2}{h} 2N$$

where the factor of 2 comes from electron spin degeneracy.

- 3. This theory has been validated by experiment with a quantum wire circuit setup that revealed a stair-step plot of conductance as a function of input voltage.
- 4. We have ignored the fact that the electrons interact and experience interactions off of one another (calculations effectively carried out at zero temperature). As a result, these resistances do not necessarily add in series.

### 1.4 Inelastic Scattering

In the field of inelastic scattering, we typically consider the situation of a particle scattering off of a quantum mechanical system. This system could be a liquid, a solid, a nuclei... anything, really. The inelastic condition implies that the act of scattering transfers energy between the particle and the target.

#### 1.4.1 Setup and Notation

To ease the theory, we will suppose that the "target" will be composed of particles with position operators  $\mathbf{R}_i$  and momentum operators  $\mathbf{P}_i$ . The incident particle will have position operator  $\mathbf{R}$  and  $\mathbf{P}$ . The Hamiltonian of the system will be

$$\hat{\mathscr{H}} = \frac{\mathbf{P}^2}{2m} + \hat{H} + V$$

Where the first term is the kinetic energy of the particle, the non-script Hamiltonian is the internal energy of the target (kinetic plus potential), and the term V is the interaction potential. To simplify the system, we shall assume that the interaction potential takes on the form

$$V = \sum_{i=1}^{N} V(\mathbf{R} - \mathbf{R}_i)$$

**Density Operator** It becomes useful to define a density operator for the target. It is

$$\rho(\mathbf{r}) = \sum_{i=1}^{N} \delta^3(\mathbf{r} - \mathbf{R}_i)$$

where  $\mathbf{r}$  is simply a c-number position coordinate (multiplied by identity). We will use the Fourier transform of this operator,

$$\rho(\mathbf{q}) = \int d^3 \mathbf{r} \, e^{-i\mathbf{q} \cdot \mathbf{r}} \rho(\mathbf{r}) = \sum_{i=1}^N e^{-i\mathbf{q} \cdot \mathbf{R}_i}$$

**Rewriting the Interaction Potential** This density operator can help us rewrite the potential into a more useful form:

$$V = \sum_{i=1}^{N} \int \frac{d^{3}\mathbf{q}}{(2\pi)^{3}} V(\mathbf{q}) e^{i\mathbf{q} \cdot (\mathbf{R} - \mathbf{R}_{i})} = \int \frac{d^{3}\mathbf{q}}{(2\pi)^{3}} V(\mathbf{q}) \rho(\mathbf{q}) e^{i\mathbf{q} \cdot \mathbf{R}}$$
(1)

which is just the definition of the Fourier Transform of the interaction potential in the first line, and then a re-expression in terms of the density operator in the second line.

#### 1.4.2 Modeling Scattering

Fermi's Golden Rule Suppose we start with an initial state  $|\mathbf{k}; E_i, \alpha\rangle$ , where  $\mathbf{k}$  is the wavevector of the incoming particle,  $E_i$  is the initial internal energy of the target and  $\alpha$  indexes the particular state with energy E (since there may be degeneracy). If we end with a final state  $|\mathbf{k}'; E_f, \beta\rangle$ , then Fermi's Golden Rule tells us

$$\Gamma_{i \to f} = \frac{2\pi}{\hbar} \left| \langle \mathbf{k}'; E_f, \beta | V | \mathbf{k}; E_i, \alpha \rangle \right|^2 \delta(E_f + \epsilon_{k'} - E_i - \epsilon_k)$$

Where the delta function maintains energy conservation (fuck you Bill). For brevity, we'll denote the matrix element as  $V_{fi}$ . In terms of the interaction potential, this matrix element is then, using equation 1,

$$V_{fi} = \int \frac{d^3 \mathbf{q}}{(2\pi)^3} V(\mathbf{q}) \langle \mathbf{k}'; E_f \beta | \rho(\mathbf{q}) e^{i\mathbf{q} \cdot \mathbf{R}} | \mathbf{k}; E_i \alpha \rangle$$
 (2)

We now make use of the fact that the momentum and position operators are conjugate operators:

$$e^{ia\hat{p}/\hbar} |x\rangle = |x+a\rangle$$

$$e^{iq\hat{x}} |k\rangle = |k+q\rangle$$

So now we have

$$e^{i\mathbf{q}\cdot\mathbf{R}}|\mathbf{k}\rangle = |\mathbf{k} + \mathbf{q}\rangle$$

Now, the state ket we have written is really a direct product,

$$|\mathbf{k}; E_i, \alpha\rangle = |\mathbf{k}\rangle \otimes |E_i, \alpha\rangle.$$
 (3)

Since **R** only acts on the portion of the direct product pertaining to the incoming particle, and  $\rho(\mathbf{q})$  only acts on the portion of the direct product pertaining to the target, we can write,

$$\langle \mathbf{k}'; E_f, \beta | \rho(\mathbf{q}) e^{i\mathbf{q} \cdot \mathbf{R}} | \mathbf{k}; E_i, \alpha \rangle = \langle E_f, \beta | \rho(\mathbf{q}) | E_i, \alpha \rangle \langle \mathbf{k}' | e^{i\mathbf{q} \cdot \mathbf{R}} | \mathbf{k} \rangle$$
 (4)

$$= \langle E_f, \beta | \rho(\mathbf{q}) | E_i, \alpha \rangle \langle \mathbf{k}' | \mathbf{k} + \mathbf{q} \rangle = \langle E_f \beta | \rho(\mathbf{q}) | E_i \alpha \rangle \delta^3(\mathbf{k}' - \mathbf{k} - \mathbf{q})$$
 (5)

Thus the matrix element can be written as, using equations 2, 4 and 5,

$$V_{fi} = \frac{V(\mathbf{k}' - \mathbf{k})}{(2\pi)^3} \langle E_f \beta | \rho(\mathbf{k}' - \mathbf{k}) | E_i \alpha \rangle$$

Now we are interested in calculating the differential cross-section, which is

$$\left(\frac{d^2\sigma}{d\epsilon\,d\Omega}\right)d\Omega\,d\epsilon \equiv \frac{\text{\# of scattered particles/time into solid angle }d\Omega \text{ and energy }\epsilon \to \epsilon + d\epsilon}{\text{\# of incident particles/time-area}}$$

Then using Fermi's Golden Rule,

$$\Gamma_{i \to d\Omega \, d\epsilon} = \Gamma_{i \to f} k'^2 dk' \, d\Omega = \Gamma_{i \to f} \left(\frac{m}{\hbar^2}\right) k' \, d\epsilon \, d\Omega$$

With

$$\epsilon = \frac{\hbar^2 k'^2}{2m} \Rightarrow d\epsilon = \frac{\hbar^2}{m} k' dk'$$

The differential cross section is now

$$\frac{d^{2}\sigma}{d\Omega d\epsilon} = \frac{\sum_{E_{f},\beta} \left(\frac{m}{\hbar^{2}}\right) k' \Gamma_{i \to f}}{\left(\frac{1}{2\pi}\right)^{3} \left(\frac{\hbar k}{m}\right)} = \left(\frac{m}{2\pi\hbar^{2}}\right)^{2} \left|V(\mathbf{k'} - \mathbf{k})\right|^{2} \frac{k'}{k} \sum_{E_{f},\beta} \delta(E_{f} + \epsilon_{k'} - E_{i} - \epsilon_{k}) \left|\langle E_{f} \beta | \rho(\mathbf{k'} - \mathbf{k}) | E_{i} \alpha \rangle\right|^{2}$$

**Dynamical Structure Factor** To simplify the form of the cross-section, we introduce the dynamical structure factor (DSF), defined as

$$S(\mathbf{q}, \omega) = \sum_{E_f, \beta} \delta \left( \omega + \frac{E_f - E_i}{\hbar} \right) \left| \langle E_f \beta | \rho(\mathbf{q}) | E_i \alpha \rangle \right|^2$$

where the DSF pertains only to the *target*, and for now  $\omega$  is just a parameter. In terms of the DSF, we can write the cross-section as

$$\frac{d^2\sigma}{d\Omega\,d\epsilon} = \left(\frac{m}{2\pi\hbar^2}\right)^2 \left|V(\mathbf{k}' - \mathbf{k})\right|^2 \frac{k'}{k} S(\mathbf{q}, \epsilon_{k'} - \epsilon_k). \tag{6}$$

where we are careful to note that the term V which appears is the Fourier transform of the potential. We now want to find a way to simplify the expression for the DSF. Rewriting the delta function,

$$S(\mathbf{q},\omega) = \sum_{E_f \beta} \int dt \, e^{i\omega t} e^{i(E_f - E_i)t/\hbar} \langle E_i \alpha | \rho(-\mathbf{q}) | E_f \beta \rangle \langle E_f \beta | \rho(\mathbf{q}) | E_i \alpha \rangle$$
 (7)

which can be further simplified by noting that, since the kets are energy eigenstates,

$$e^{it(E_f - E_i)/\hbar} \langle E_f \beta | \rho(\mathbf{q}) | E_i \alpha \rangle = \langle E_f \beta | e^{iHt/\hbar} \rho(\mathbf{q}) e^{-iHt/\hbar} | E_i \alpha \rangle$$
 (8)

So the dynamical structure factor is then

$$S(\mathbf{q},\omega) = \sum_{E_f,\beta} \int dt \, e^{i\omega t} \left\langle E_i \, \alpha \, | \rho(-\mathbf{q}) | \, E_f \, \beta \right\rangle \left\langle E_f \, \beta \, \left| e^{iHt/\hbar} \rho(\mathbf{q}) e^{-iHt/\hbar} \right| \, E_i \, \alpha \right\rangle \tag{9}$$

Since we now see we have a completeness relation, we can perform the summation to get

$$S(\mathbf{q},\omega) = \int \frac{dt}{2\pi} e^{i\omega t} \langle E_i \alpha | \rho(-\mathbf{q}, 0) \rho(\mathbf{q}, t) | E_i \alpha \rangle, \qquad (10)$$

which is a particularly useful form since it involves the expectation value of some operator in the initial state of the target particle. Equations 6 and 10 are the results we will most often want to use (in particular for HW1 P3!). Note that  $\rho(\mathbf{q},t)$  is just the second operator sandwiched in equation 9, which corresponds to the usual Heisenberg picture definition.

**Thermal Targets** For a thermodynamic situation with the target at some temperature T, for some operator  $\hat{\theta}$ ,

$$\left\langle \hat{\mathcal{O}} \right\rangle \equiv \frac{1}{Z} \sum_{E,\alpha} e^{-\beta E} \left\langle E_{\alpha} \left| \hat{\mathcal{O}} \right| E \alpha \right\rangle; \qquad Z = \sum_{E\alpha} e^{-\beta E}$$

$$S(\mathbf{q}, \omega) = \int \frac{dt}{2\pi} e^{i\omega t} \langle \rho(-\mathbf{q}, 0) \rho(\mathbf{q}, t) \rangle$$

#### Some Comments

1. If we don't measure the final energy (i.e. we measure the *direction*),

$$S_{\text{static}}(\mathbf{q}) = \int d\omega S(\mathbf{q}, \omega) = \langle \rho(-\mathbf{q})\rho(\mathbf{q}) \rangle = \left\langle \left| \sum_{i} e^{-\mathbf{q} \cdot \mathbf{R}_{i}} \right|^{2} \right\rangle$$

2. If the target particles are very heavy (i.e. they do not move),

$$\rho(\mathbf{q},t) = \rho(\mathbf{q})$$

and

$$S(\mathbf{q}, \omega) = S(\omega) S_{\mathrm{static}}(\mathbf{q})$$

3. (MISSING IMPORTANT FIGURE)

For particles traveling with a path length difference, a phase difference is accumulated:

$$\Delta \phi_i = \frac{2\pi}{\lambda} \hat{R}_i \hat{k} - \frac{2\pi}{\lambda'} \hat{R}_i \hat{k}' = \mathbf{R}_i \cdot (\mathbf{k} - \mathbf{k}') = -\mathbf{R}_i \cdot \mathbf{q}$$

$$Amp \approx \sum_{i} e^{i\Delta\phi_i} \cong \sum_{i} e^{-i\mathbf{q}\cdot\mathbf{R}_i} = \rho(\mathbf{q})$$

So the scattered intensity is

$$S(\mathbf{q}) \sim \langle |\text{Amp}| \rangle = \langle \rho(\mathbf{q}) \rho(-\mathbf{q}) \rangle$$

#### 1.4.3 Scattering Examples

Suppose we scatter off of a solid or liquid with length scale  $a \sim 3\text{Å}$  and energy scale  $k_B T_{\text{room}} \sim 300\,\text{K}$ .

#### Light Scattering

$$\epsilon = \hbar\omega = \hbar ck = \frac{hc}{\lambda} \approx 10^4 \,\mathrm{eV} \sim 10^7 \,\mathrm{K}$$

$$\Delta \epsilon \sim 300 \,\mathrm{K}$$

This is in fact X-Ray scattering. April 4, 2011

#### **Electron Scattering**

$$\epsilon_e = \frac{h^2}{2m\lambda^2} \approx 100 \,\mathrm{eV}$$

[MISSING INFORMATION]

#### Neutrons

$$\epsilon_{
m N} \sim \frac{h^2}{M_{
m p} \lambda^2} \approx 0.1 \, {
m ev} \sim 1000 \, {
m K}$$

Neutrons interact with nuclei through the strong interactions as well as electrons through their spins.

## 2 Quantum Hall Effect

#### 2.1 References

- 1. The Quantum Hall Effect by Prange and Girvin
- 2. Perspectives in Quantum Hall Effects by daw Sarma and Pinczuk

#### 2.2 Flavors of the Quantum Hall Effect

The first manifestation of the Quantum Hall Effect (QHE) was discovered in 1979. It is called the **Integer Quantum Hall Effect**, for which a Nobel prize was issued in 1985. Shortly thereafter, in 1982 the **Fractional Quantum Hall Effect** was discovered by Bob Laughlin, Tsui, Gossard, and Storium, for which all but Gossard were awarded a Nobel prize.

#### 2.3 Basic Setup

To "make" a QHE apparatus, one grows a Silicon MOSFET (Metal Oxide (something)-Fueled (something) Transistor) with a metallic gate over a Silicon Oxide layer. A bias voltage is placed between the metallic gate and the Silicon.

This creates a two-dimensional electron gas by restricting the system to one transverse mode in one of the dimensions (like the quantum wire with an additional free direction).

#### 2.3.1 Integer Quantum Hall Effect

The resistance along the longitudinal direction is

$$R_L = \frac{V_L}{I} = \frac{V_A - V_B}{I}$$

and the so-called "Hall Resistance" is

$$R_H = \frac{V_A - V_C}{I}$$

If a magnetic field is applied, the hall resistance grew in a stair-step fashion, with values  $R_H$ 

#### Figure 3: USEFUL "VIEW FROM TOP" DIAGRAM

 $h/(ne^2)$  with n an integer, and except for values of B where  $R_H$  jumped,  $R_L$  was zero.

#### 2.3.2 Fractional Quantum Hall Effect

From measuring the hall conductance,  $G_H = 1/R_H$ , it was found that

$$G_H = \frac{p}{q} \left( \frac{e^2}{h} \right)$$

where p is an integer and q is an odd integer. The ratio of these two (the fraction in the conductance) is often called the **Filling Factor**, and several prevalent fractions that have been recorded are

$$L \equiv p/q = 1/3, 2/3, 1/5, 2/5, 3/5, 4/5, \dots$$

#### 2.4 Details of the Quantum Hall Effect

In the semiconductor, electrons are moving in a net direction across the material (we'll call that direction the x-direction), creating an electric field. If we Lorentz Boost to a frame at that velocity,

$$\mathbf{v} = \frac{1}{c} \frac{\mathbf{E} \times \mathbf{B}}{B^2},$$

then the electric field is effectively reduced to zero.

At this velocity, we can calculate the electric current,  $\mathbf{J}$ , given the number density, n:

$$J = nev$$

We then have

$$J_x = \frac{ne}{cB}E_y$$

We define the **Resistivity Tensor** to be

$$\rho = \begin{pmatrix} \rho_{xx} & \rho_{xy} \\ -\rho_{xy} & \rho_{yy} \end{pmatrix}$$

The electric field is then given by

$$\mathbf{E} \equiv \rho \mathbf{J}$$

If the width of the material is W and the length between the voltage probes is L, we have

$$J_x = I/W$$

and so

$$E_x = \rho_{yx} J_x$$

So

$$R_H \equiv \rho_{xy} = \frac{V_y/W}{I/W} = \frac{V_y}{I}$$

where we also have

$$R_H = \rho_{xy} = \frac{B}{nec}$$

And also

$$\rho_{xx} = \frac{E_x}{J_x}$$

$$= \frac{V_x/L}{I/W}$$

$$= R_L(W/L)$$

$$= 0$$

#### 2.4.1 Impurity Scattering

We assume scattering off of impurities to be elastic. We can obtain a **scattering time**,  $\tau$  from Fermi's Golden Rule and a drift velocity  $\mathbf{v}_d$  for the electrons. The force on the electrons is then

$$m\frac{d\mathbf{v}_d}{dt} = e\mathbf{E} + \frac{e}{c}\mathbf{v} \times \mathbf{B}$$
$$= -m\frac{\mathbf{v}}{\tau}$$

This technique is called **Drude Theory**. We can use this to express the components of the resistivity tensor:

$$\rho_{xx} = \frac{m}{ne^2\tau}$$

$$\rho_{xy} = \frac{1}{nec}$$

Note that we have non-zero  $\rho_{xx}$  and no plateaus on  $\rho_{xy}$ . This is thus a semi-classical approach.

April 6, 2011

#### 2.4.2 Integer Quantum Hall Effect

Consider now a 2D electron gas with a magnetic field normal to it. Let's say,  $\mathbf{B} = B_0 \hat{z}$  (See Figure 4). We will work in the Landau gauge, where  $A_x = -B_y$  and  $A_y = 0 = A_z$ . Then we have a

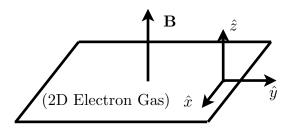


Figure 4: 2D Gas of Non-Interacting Electrons

Hamiltonian

$$\hat{H} = \frac{1}{2m} \left( \mathbf{p} - \frac{e\mathbf{A}}{c} \right)^2$$

or

$$\hat{H} = \frac{1}{2m} \left( p_x - \frac{eB_y}{c} \right)^2 + \frac{p_y^2}{2m}$$

Since this Hamiltonian is independent of x, we write the wave function of the electron as

$$\psi(x,y) = e^{ik_x x} \phi(y)$$

where  $\hat{H}\psi = E\psi$ . Then employing Schrödinger's equation,

$$\left(-\frac{\hbar^2}{2m}\partial_y^2 + \frac{1}{2}m\omega_c^2(y - y_0)^2\right)\phi(y) = E\phi(y)$$

where the cyclotron frequency,  $\omega_c$  is defined as  $\omega_c \equiv \frac{eB}{mc}$ , and the equilibrium value of y is  $y_0 \equiv k_x \ell^2$ , where we have introduced the magnetic length,

$$\ell = \sqrt{\frac{\hbar c}{eB}} = \sqrt{\frac{\hbar}{m\omega_c}}$$

For perspective,  $\hbar\omega_c$  in a 1 Tesla field is equivalent to 1 K,  $\ell$  is about 200 Å.

#### 2.4.3 Landau Levels

Allowed energies must follow the form of the harmonic oscillators:

$$E_n = \hbar\omega_c \left( n + \frac{1}{2} \right)$$

since the Hamiltonian is identical to the quantum harmonic oscillator (a nice product of gauge choice), which then gives energy eigenfunctions

$$\psi_n = e^{ik_x x} e^{-(y-y_0)^2/\ell^2} H_n\left(\frac{y-y_0}{\ell}\right)$$

Of interest are the Landau levels, which are highly degenerate, as shown in Figure 5. This is because the Hamiltonian does not depend on  $k_x$ , allowing large number of available states to have the same energy (Check out *Wikipedia*'s entry on Landau Levels!). If we confine the system to a

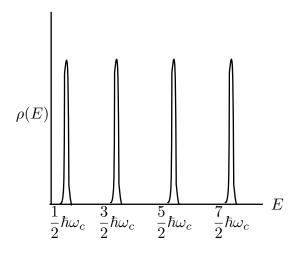


Figure 5: Density of States of the Landau Levels

box of dimensions  $L_x$  and  $L_y$ , the number of wave numbers  $k_x$  is limited to  $k_x = \frac{2\pi n}{l_x}$  for some integer n. This is from the boundary condition that mandates  $\exp(ik_xL_x) = \exp(ik_x0) = 1$ . This quantization of the wave number necessarily quantizes  $y_0$  as well, as

$$y_0 = k_x \ell^2 = \frac{2\pi n}{L_x} \ell^2 \Rightarrow \Delta y = \frac{2\pi}{L_x} \ell^2$$

Thus the available states for each Landau level have the form  $e^{ik_xx}$  in the x direction but must necessarily be separated by some multiple of  $\Delta y$ , as is reflected in Figure 6. Since any of these states are accessible, the total number of states is then given by the ratio of  $L_y$  and  $\Delta y$  (since the state must necessarily be in the box)

$$N_{LL} = \frac{L_y}{\Delta y} = \frac{L_x L_y}{2\pi \ell^2}$$

For the number density, we want

$$n_{LL}=\frac{N_{LL}}{L_xL_y}=\frac{1}{2\pi\ell^2}=\frac{B}{\Phi_0}$$

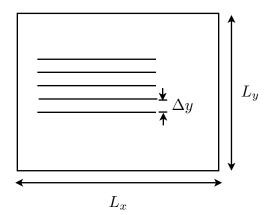


Figure 6: Spacing of the Degenerate Landau Level States

where  $\Phi_0 = hc/e$  is the flux quantum. The flux quantum is defined as the amount of flux required for an electron to pick up a phase factor of  $2\pi$  while orbiting around the flux. Then we have

$$N_{LL} = \frac{BL_xL_y}{\Phi_0} = \frac{\text{total flux}}{\text{quantum of flux}}$$

We define the filling factor  $\nu$  to be

$$\nu \equiv \frac{N}{N_{LL}} = \frac{\#e^-}{\# \text{ vertices}}$$

In the integer quantum hall effect,  $\nu$  is an integer, and in the fractional quantum hall effect,  $\nu = p/q$  for any integer p and any odd integer q. Suppose we have just enough electrons to fill the lowest Landau Level. Then we have

$$R_H = \frac{B}{nec}$$

replacing n with  $n_{LL}$ , we have

$$R_H^{LL} = \frac{B}{n_{LL}ec} = \frac{B}{\frac{B}{\Phi_0}ec} = \frac{h}{e^2}$$

#### 2.4.4 Edge Effects

Suppose we have a particle in a box in with a confining potential V(y) that keeps the particle from escaping the box. Then the Hamiltonian goes to

$$\hat{H} \rightarrow \hat{H} + V(y)$$

The wavefunction is still

$$\psi = e^{ik_x x} \phi(y)$$

and it now satisfies

$$\left(-\frac{\hbar^2}{2m}\partial_y^2 + \frac{1}{2}m\omega_c^2(y - y_0)^2 + V(y)\right)\phi(y) = E\phi(y)$$

If we assume that V(y) varies slowly near  $y_0$  on the scale of  $\ell$ , we may approximate the confining potential as

$$V(y) = V(y_0) + V'(y_0)(y - y_0) + \dots \approx V(y_0)$$

then the energy levels are shifted

$$E_n = \hbar\omega_c \left( n + \frac{1}{2} \right) + V(y_0)$$

Interestingly, these excitations on the edge states are quite similar to one-dimensional Landauer transport, and it corresponds roughly to electrons "skipping" along the edge.